

# PMEG100T100ELPE

100 V, 10 A low leakage current Trench MEGA Schottky barrier rectifier

3 December 2020

Product data sheet

### 1. General description

Trench Maximum Efficiency General Application (MEGA) Schottky barrier rectifier encapsulated in a CFP15B (SOT1289B) power and flat lead Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- Low forward voltage
- Low Q<sub>rr</sub> and low I<sub>RM</sub>
- · Low leakage current
- · High power capability due to clip-bonding technology
- Small and flat lead SMD power plastic package
- AEC-Q101 qualified

### 3. Applications

- High efficiency DC-to-DC conversion
- · Automotive LED lighting
- · Switch mode power supply
- Freewheeling application
- Reverse polarity protection
- OR-ing

### 4. Quick reference data

Table 1. Quick reference data

| Symbol             | Parameter               | Conditions   |     | Min | Тур  | Max | Unit |
|--------------------|-------------------------|--|-----|-----|------|-----|------|
| I <sub>F(AV)</sub> | average forward current | $\delta$ = 0.5; square wave; f = 20 kHz; T <sub>sp</sub> $\leq$ 162 °C |     | -   | -    | 10  | А    |
| V <sub>R</sub>     | reverse voltage         | T <sub>j</sub> = 25 °C   |     | -   | -    | 100 | V    |
| V <sub>F</sub>     | forward voltage         | I <sub>F</sub> = 10 A; pulsed; T <sub>j</sub> = 25 °C                  | [1] | -   | 750  | 810 | mV   |
| I <sub>R</sub>     | reverse current         | V <sub>R</sub> = 100 V; pulsed; T <sub>j</sub> = 25 °C                 | [1] | -   | 0.85 | 5   | μΑ   |
|                    |                         | V <sub>R</sub> = 100 V; pulsed; T <sub>j</sub> = 125 °C                | [1] | -   | 1.25 | 6   | mA   |

[1] Very short pulse, in order to maintain a stable junction temperature.



# 5. Pinning information

#### **Table 2. Pinning information**

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--------------------|----------------|
| 1   | Α      | anode       | 5                  | ⊬ [P] □A       |
| 2   | Α      | anode       |                    | A aaa-009063   |
| 3   | K      | cathode     | 2                  | aaa-009063     |
|     |        |             | CFP15B (SOT1289B)  |                |

# 6. Ordering information

#### **Table 3. Ordering information**

| Type number     | Package |  |          |  |  |  |  |  |
|-----------------|---------|--|----------|--|--|--|--|--|
|                 | Name    | Description  | Version  |  |  |  |  |  |
| PMEG100T100ELPE | CFP15B  | plastic, thermal enhanced ultra thin SMD package; 3 leads; 2.13 mm pitch; $5.8 \times 4.3 \times 0.95$ mm body | SOT1289B |  |  |  |  |  |

### 7. Marking

#### Table 4. Marking codes

| Type number     | Marking code |
|-----------------|--------------|
| PMEG100T100ELPE | 100T         |
|                 | L10E         |

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC60134).

| Symbol             | Parameter                           | Conditions  |     | Min | Max  | Unit |
|--------------------|-------------------------------------|---|-----|-----|------|------|
| V <sub>R</sub>     | reverse voltage                     | T <sub>j</sub> = 25 °C  |     | -   | 100  | V    |
| I <sub>F</sub>     | forward current                     | $\delta$ = 1; $T_{sp} \le 158 ^{\circ}\text{C}$                   |     | -   | 14.1 | Α    |
| I <sub>F(AV)</sub> | average forward current             | $\delta$ = 0.5; square wave; f = 20 kHz; T <sub>sp</sub> ≤ 162 °C |     | -   | 10   | А    |
| I <sub>FSM</sub>   | non-repetitive peak forward current | $t_p$ = 8.3 ms; half sine wave; $T_{j(init)}$ = 25 °C             |     | -   | 180  | А    |
| P <sub>tot</sub>   | total power dissipation             | T <sub>amb</sub> ≤ 25 °C  | [1] | -   | 1.66 | W    |
|                    |                                     |   | [2] | -   | 2.15 | W    |
| Tj                 | junction temperature                |   |     | -   | 175  | °C   |
| T <sub>amb</sub>   | ambient temperature                 |   |     | -55 | 175  | °C   |
| T <sub>stg</sub>   | storage temperature                 |   |     | -65 | 175  | °C   |

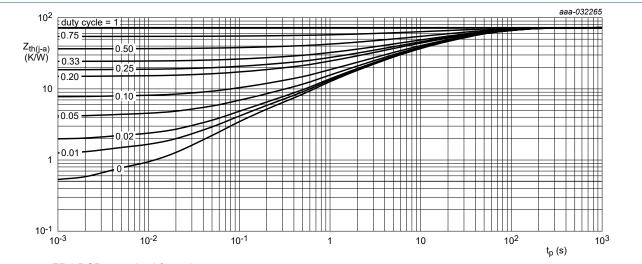
- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

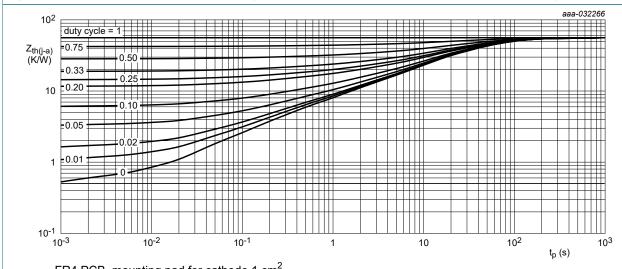
| Symbol                | Parameter  | Conditions  |         | Min | Тур | Max | Unit |
|-----------------------|--|-------------|---------|-----|-----|-----|------|
| R <sub>th(j-a)</sub>  | thermal resistance from                          | in free air | [1] [2] | -   | -   | 90  | K/W  |
| junction to ambient   | junction to ambient                              |             | [1] [3] | -   | -   | 70  | K/W  |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |             | [4]     | -   | -   | 7   | K/W  |

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.
- 2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.
- [4] Soldering point of cathode tab.



FR4 PCB, standard footprint

Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>

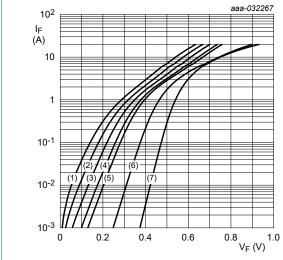
Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### 10. Characteristics

**Table 7. Characteristics** 

| Symbol          | Parameter                           | Conditions   |     | Min | Тур  | Max | Unit |
|-----------------|-------------------------------------|--|-----|-----|------|-----|------|
| $V_{(BR)R}$     | reverse breakdown<br>voltage        | I <sub>R</sub> = 1 mA; T <sub>j</sub> = 25 °C  | [1] | 100 | -    | -   | V    |
| V <sub>F</sub>  | forward voltage                     | I <sub>F</sub> = 1 A; pulsed; T <sub>j</sub> = 25 °C   | [1] | -   | 460  | 520 | mV   |
|                 |                                     | I <sub>F</sub> = 3 A; pulsed; T <sub>j</sub> = 25 °C   | [1] | -   | 545  | 610 | mV   |
|                 |                                     | I <sub>F</sub> = 5 A; pulsed; T <sub>j</sub> = 25 °C   | [1] | -   | 620  | 690 | mV   |
|                 |                                     | I <sub>F</sub> = 8 A; pulsed; T <sub>j</sub> = 25 °C   | [1] | -   | 705  | 780 | mV   |
|                 |                                     | I <sub>F</sub> = 10 A; pulsed; T <sub>j</sub> = 25 °C  | [1] | -   | 750  | 810 | mV   |
|                 |                                     | I <sub>F</sub> = 10 A; pulsed; T <sub>j</sub> = -40 °C   | [1] | -   | 755  | 820 | mV   |
|                 |                                     | I <sub>F</sub> = 10 A; pulsed; T <sub>j</sub> = 125 °C   | [1] | -   | 615  | 690 | mV   |
|                 |                                     | I <sub>F</sub> = 10 A; pulsed; T <sub>j</sub> = 150 °C   | [1] | -   | 580  | 650 | mV   |
| I <sub>R</sub>  | reverse current                     | V <sub>R</sub> = 60 V; pulsed; T <sub>j</sub> = 25 °C  | [1] | -   | 0.3  | 1.5 | μΑ   |
|                 |                                     | $V_R$ = 100 V; pulsed; $T_j$ = 25 °C   | [1] | -   | 0.85 | 5   | μA   |
|                 |                                     | V <sub>R</sub> = 100 V; pulsed; T <sub>j</sub> = 125 °C  | [1] | -   | 1.25 | 6   | mA   |
|                 |                                     | V <sub>R</sub> = 100 V; pulsed; T <sub>j</sub> = 150 °C  | [1] | -   | 4.8  | 25  | mA   |
| C <sub>d</sub>  | diode capacitance                   | V <sub>R</sub> = 1 V; f = 1 MHz; T <sub>j</sub> = 25 °C  |     | -   | 850  | -   | pF   |
|                 |                                     | V <sub>R</sub> = 10 V; f = 1 MHz; T <sub>j</sub> = 25 °C   |     | -   | 240  | -   | pF   |
| t <sub>rr</sub> | reverse recovery time step recovery | $I_F = 0.5 \text{ A}; I_R = 0.5 \text{ A}; I_{R(meas)} = 0.1 \text{ A};$<br>$T_j = 25 \text{ °C}$      |     | -   | 22   | -   | ns   |
|                 | reverse recovery time ramp recovery | $dI_F/dt = 200 \text{ A/}\mu\text{s}; I_F = 6 \text{ A}; V_R = 26 \text{ V};$<br>$T_j = 25 \text{ °C}$ |     | -   | 13   | -   | ns   |
| I <sub>RM</sub> | peak reverse recovery current       |  |     | -   | 1.3  | -   | Α    |
| Q <sub>rr</sub> | reverse recovery charge             | $dI_F/dt = 200 \text{ A/s}; I_F = 6 \text{ A}; V_R = 26 \text{ V};$<br>$T_j = 25 \text{ °C}$           |     | -   | 11.5 | -   | nC   |
| $V_{FRM}$       | peak forward recovery voltage       | $I_F = 0.5 \text{ A}; \text{ d}I_F/\text{d}t = 20 \text{ A/µs}; T_j = 25 ^{\circ}\text{C}$             |     | -   | 415  | -   | mV   |

<sup>[1]</sup> Very short pulse, in order to maintain a stable junction temperature.



pulsed condition

(1) Tj = 175 °C

(2) Tj = 150 °C

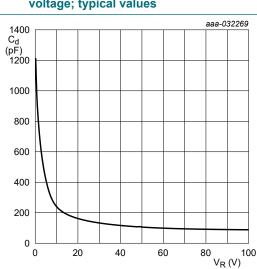
(3) Tj = 125 °C

(4) Tj = 100 °C

(5) Tj = 85 °C (6) Tj = 25 °C

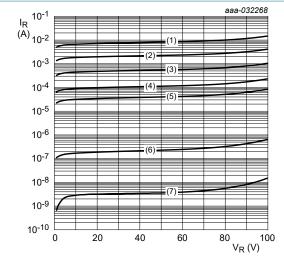
(7) Tj = -40 °C

Fig. 3. Forward current as a function of forward voltage; typical values



 $f = 1 MHz; T_{amb} = 25 °C$ 

Fig. 5. Diode capacitance as a function of reverse voltage; typical values



pulsed condition

 $(1) T_i = 175 °C$ 

(2)  $T_i = 150 °C$ 

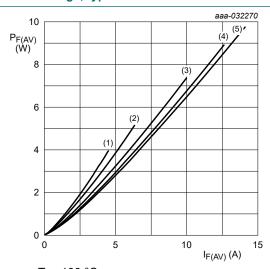
 $(3) T_i = 125 °C$ 

 $(4) T_i = 100 °C$ 

 $(5) T_j = 85 ^{\circ}C$ 

(6)  $T_j = 25 \,^{\circ}\text{C}$ (7)  $T_i = -40 \,^{\circ}\text{C}$ 

Fig. 4. Reverse current as a function of reverse voltage; typical values



 $T_j = 100 \, ^{\circ}C$ 

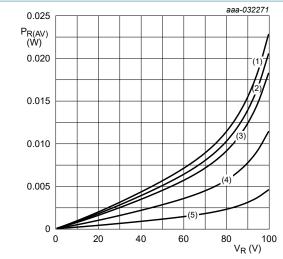
 $(1) \delta = 0.1$ 

 $(2) \delta = 0.2$ 

 $(3) \delta = 0.5$ 

(4)  $\delta = 1$ ; DC

Fig. 6. Average forward power dissipation as a function of average forward current; typical values



T<sub>i</sub> = 100 °C

 $(1) \delta = 1$ ; DC

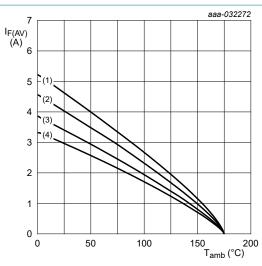
 $(2) \delta = 0.9$ 

 $(3) \delta = 0.8$ 

 $(4) \delta = 0.5$ 

 $(5) \delta = 0.2$ 

Fig. 7. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

T<sub>i</sub> = 175 °C

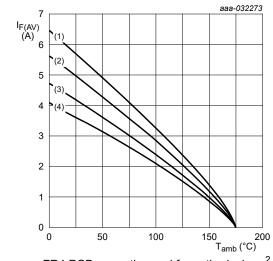
 $(1) \delta = 1$ ; DC

(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta = 0.1$ ; f = 20 kHz

Fig. 8. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>

T<sub>i</sub> = 175 °C

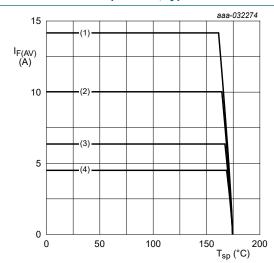
 $(1) \delta = 1; DC$ 

(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta = 0.1$ ; f = 20 kHz

Fig. 9. Average forward current as a function of ambient temperature; typical values



Tj = 175 °C

(1)  $\delta$  = 1; DC

(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta = 0.1$ ; f = 20 kHz

Fig. 10. Average forward current as a function of solder point temperature; typical values

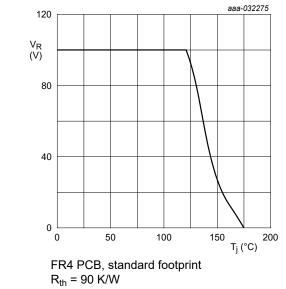
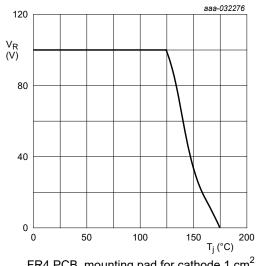
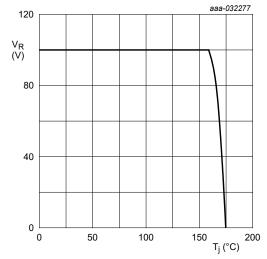


Fig. 11. Derated maximum reverse voltage as a function | Fig. 12. Derated maximum reverse voltage as a function of junction temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>  $R_{th} = 70 \text{ K/W}$ 

of junction temperature; typical values



Soldering point of cathode tab  $R_{th} = 7 \text{ K/W}$ 

Fig. 13. Derated maximum reverse voltage as a function of junction temperature; typical values

# 11. Test information

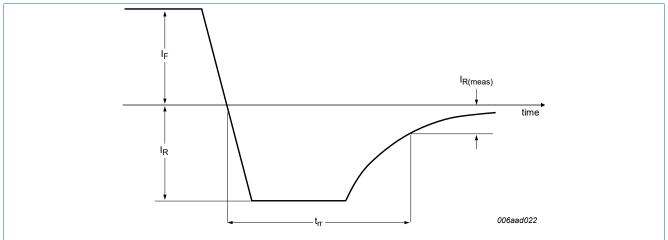


Fig. 14. Reverse recovery definition; step recovery

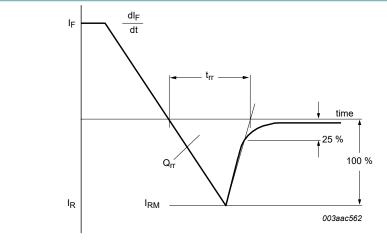


Fig. 15. Reverse recovery definition; ramp recovery

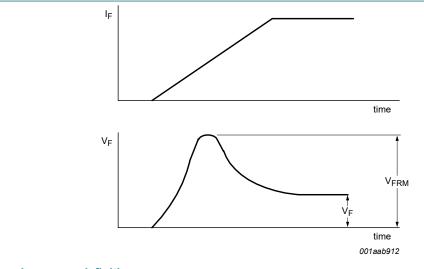
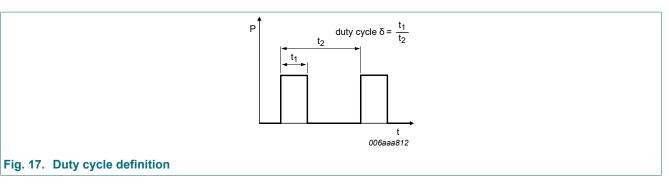


Fig. 16. Forward recovery definition

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The current ratings for the typical waveforms are calculated according to the equations:

 $I_{F(AV)}=I_M\times\delta$  with  $I_M$  defined as peak current

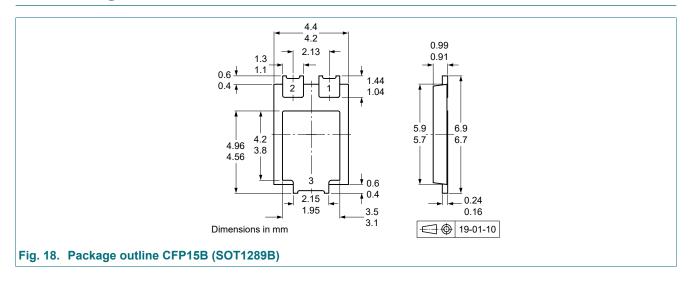
 $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$ 

with  $I_{\mbox{\scriptsize RMS}}$  defined as RMS current.

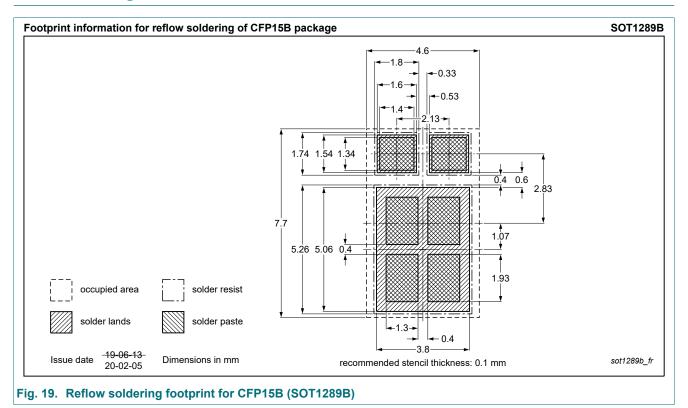
### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

# 12. Package outline



### 13. Soldering



# 14. Revision history

#### Table 8. Revision history

| Data sheet ID       | Release date      | Data sheet status      | Change notice | Supersedes          |
|---------------------|-------------------|------------------------|---------------|---------------------|
| PMEG100T100ELPE v.2 | 20201203          | Product data sheet     | -             | PMEG100T100ELPE v.1 |
| Modifications:      | Product status of | changed                |               |                     |
| PMEG100T100ELPE v.1 | 20200923          | Preliminary data sheet | -             | -                   |

### 15. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
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